

**REMARKS**

Claims 1-9 and 24-28 are pending. Of these, claims 25-28 are allowed. By this amendment, claim 1 is amended. No new matter is added.

Claim 1 is amended to clarify a claimed feature of the claim, with support found at least in FIG. 2 of the Disclosure.

It is respectfully submitted that entry of the amendment is proper as the amendment would place the application in condition for allowance or at least present the claims in better form for appeal. Further, the amendments do not raise new issues, and do not require more than nominal consideration by the Examiner.

Applicants thank Examiner Hines for the indication on page 4 of the Office Action that claims 25-28 are allowed, and claims 3-6 recite allowable subject matter.

For the following reasons, reconsideration is respectfully requested.

**REJECTION UNDER 35 U.S.C. §102:**

On page 2 of the Office Action, claims 1, 2, 7, 9, and 24 are rejected under 35 U.S.C. §102(b) over Cho (U.S. Patent Application Publication No. 2002/0043928). The rejection is respectfully traversed.

It is respectfully submitted that the feature of a lower electrode formed on the substrate, the lower electrode having a planar upper surface at a first step difference above the substrate; a pixel define layer formed on the substrate and covering one portion of the lower electrode while exposing another portion of the lower electrode, the portion of the pixel define layer, which covers the one portion of the lower electrode, having a planar upper surface at a second step difference above the substrate, wherein the second step difference of the pixel define layer is not greater than the first step difference of the lower electrode, as defined in claim 1, is patentably distinguishable over the applied reference to Cho.

Specifically, Cho discloses an interlayer insulator 140 having a portion of the interlayer insulator 140 that is formed over an anode electrode 120, and a portion of the interlayer insulator 140 that is formed directly on the substrate 110 (see, FIG. 3F of Cho). The portion of the interlayer insulator 140 that is formed over the anode electrode 120 is at a step difference

greater than a step difference of the anode electrode 120 (see, FIG. 3F of Cho). Accordingly, claim 1 that recites that the second step difference of the pixel define layer is not greater than the first step difference of the lower electrode, is patentably distinguishable over the applied reference to Cho.

Claims 2, 7, and 9, which depend from claim 1, are likewise patentably distinguishable over the applied reference for at least the reasons discussed above, and for the additional features they recite. Withdrawal of the rejection is respectfully requested.

**REJECTION UNDER 35 U.S.C. §103:**

On page 3 of the Office Action, claim 8 is rejected under 35 U.S.C. §103(a) as being unpatentable over Cho, in view of Arnold et al. (U.S. Patent No. 7,038,373). The rejection is respectfully traversed.

As discussed above, claim 1 is patentably distinguishable over the Cho reference. Arnold does not remedy the situation. Thus, claim 8, which depends from claim 1, is also patentably distinguishable over the applied references to Cho and Arnold for at least its dependence from claim 1, and for the additional features it recites. Withdrawal of the rejection is respectfully submitted.

**ALLOWABLE SUBJECT MATTER:**

On page 4 of the Office Action, claims 25-28 are indicated as allowed, and claims 3-6 are indicated as reciting allowable subject matter.

**CONCLUSION:**

There being no further outstanding objections or rejections, it is submitted that the application is in condition for allowance. An early action to that effect is courteously solicited.

Finally, if there are any formal matters remaining after this response, the Examiner is requested to telephone the undersigned to attend to these matters.

If there are any additional fees associated with filing of this Amendment, please charge the same to our Deposit Account No. 503333.

Respectfully submitted,

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